NSN 5962-01-179-0532

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-179-0532 **Body Length:** Between 1.190 inches and 1.290 inches **Body Width:** 0.610 inches **Body Height:** Between 0.090 inches and 0.170 inches **Maximum Power Dissipation Rating:** 830.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and bipolar and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 90.00 nanoseconds propagation delay time, high to low level output and 90.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig:

A458a0

Demilitarization: Yes - demil/mli